

Technical Data
Data Sheet N1233, Rev. B

Green Products

444CMQ035/444CMQ040/444CMQ045 SCHOTTKY RECTIFIER

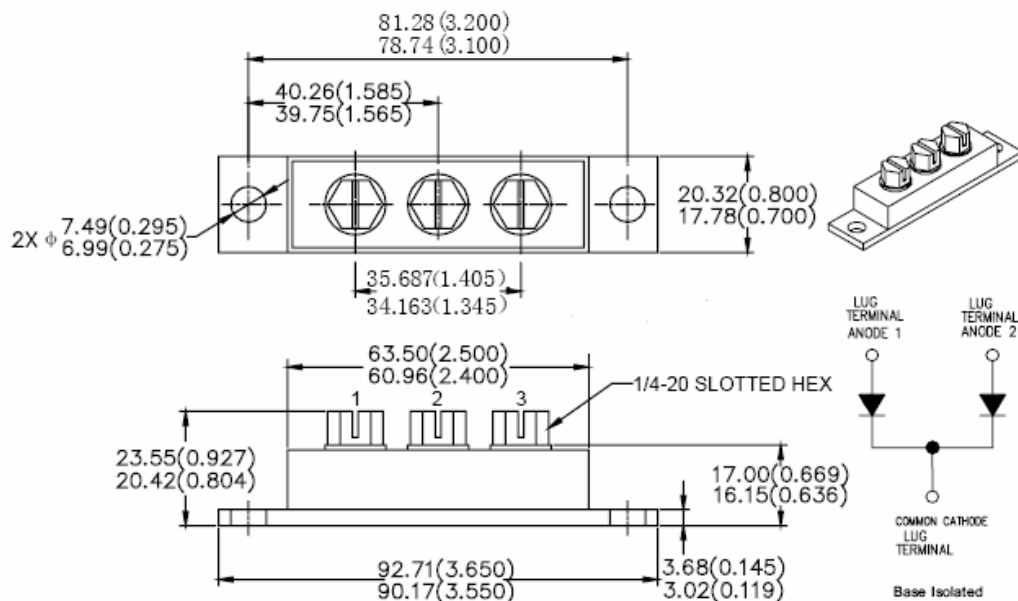
Applications:

- High current switching power supply • Plating power supply • Free-Wheeling diodes
- Reverse battery protection • Converters • UPS System • Welding

Features:

- 125°C T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm/Inches



Please Note: Anode 1 = Terminal 1; Anode 2 = Terminal 3; Common Cathode = Terminal 2
Suffix R Denotes for Reversed Polarity.

PRM4 (Isolated)

MARKING, MOLDING RESIN

Marking for 444CMQ035/040/045, 1st row SS YYWWL, 2nd row 444CMQ035/040/045

Where YY is the manufacture year

WW is the manufacture week code

L is the wafer's Lot Number

Molding resin

Epoxy resin UL:94V-0

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Maximum Ratings:

Characteristics	Symbol	Condition	Max.		Units
Peak Inverse Voltage	V_{RWM}	-	35	444CMQ035	V
			40	444CMQ040	
			45	444CMQ045	
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle @ $T_C=81^\circ\text{C}$, rectangular wave form	220	per leg	A
			440	per device	
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I_{FSM}	8.3 ms, half Sine pulse	4560		A
Non-Repetitive Avalanche Energy(peg leg)	E_{AS}	$T_J=25^\circ\text{C}$, $I_{AS}=40\text{A}$, $L=0.34\text{mH}$	270		mJ
Repetitive Avalanche Current(peg leg)	I_{AR}	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A=1.5 \times V_R$ typical	40		A

Electrical Characteristics:

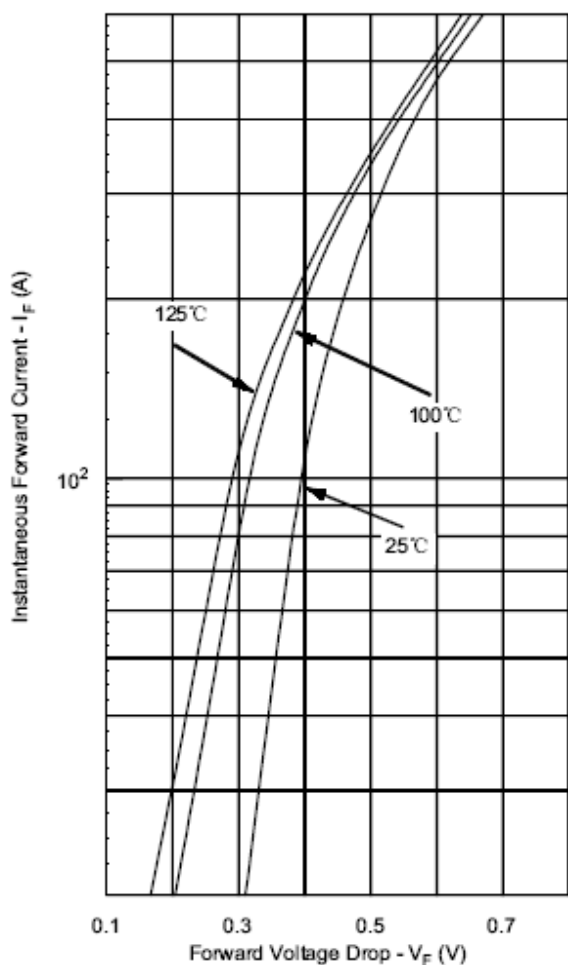
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	V_{F1}	@ 220A, Pulse, $T_J = 25^\circ\text{C}$	0.53	V
		@ 440A, Pulse, $T_J = 25^\circ\text{C}$	0.69	
Max. Reverse Current (per leg) *	I_{R1}	@ $V_R = \text{rated } V_R$ $T_J = 25^\circ\text{C}$	20	mA
		@ $V_R = \text{rated } V_R$ $T_J = 125^\circ\text{C}$	2400	
Max. Junction Capacitance (per leg)	C_T	@ $V_R = 5\text{V}$, $T_C = 25^\circ\text{C}$	10300	pF
		$f_{SIG} = 1\text{MHz}$		
Typical Series Inductance (per leg)	L_S	Measured lead to lead 5 mm from package body	5.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/ μs

 * Pulse Width < 300 μs , Duty Cycle <2%

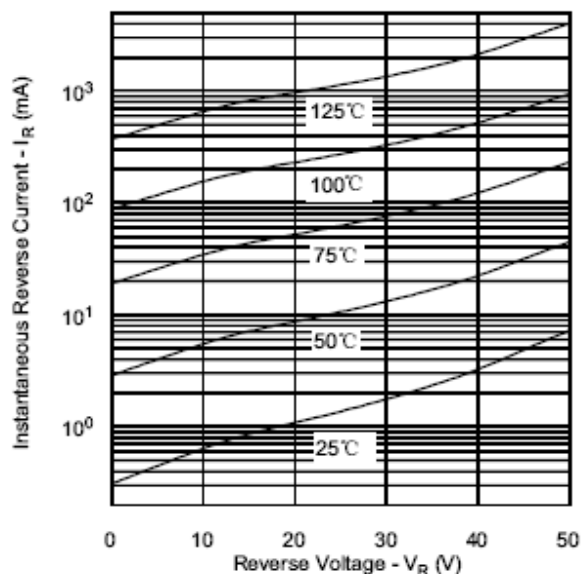
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units	
Max. Junction Temperature	T_J	-	-55 to +125	$^\circ\text{C}$	
Max. Storage Temperature	T_{stg}	-	-55 to +125	$^\circ\text{C}$	
Maximum Thermal Resistance Junction to Case (per leg)	$R_{\theta JC}$	DC operation	0.40	$^\circ\text{C/W}$	
Maximum Thermal Resistance Junction to Case (per package)	$R_{\theta JC}$	DC operation	0.20	$^\circ\text{C/W}$	
Typical Thermal Resistance, case to Heat Sink	$R_{\theta cs}$	Mounting surface, smooth and greased	0.10	$^\circ\text{C/W}$	
Mounting Torque	T_M	-	Mounting Torque	24(min) 35(max)	Kg-cm
			Terminal Torque	35(min) 46(max)	
Approximate Weight	wt	-	79	g	
Case Style	PRM4 Isolated				

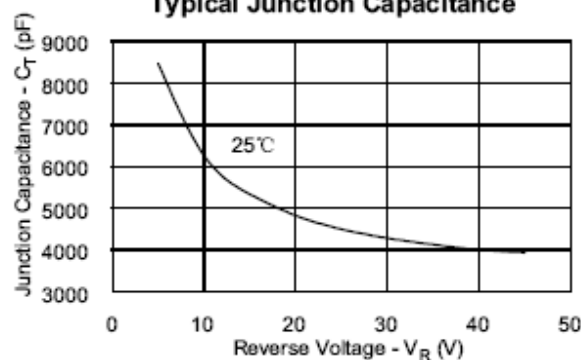
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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